

PHOTOCOUPLER

PS2535-1,PS2535L-1

HIGH COLLECTOR TO EMITTER VOLTAGE HIGH ISOLATION VOLTAGE MULTI PHOTOCOUPLER SERIES

-NEPOC Series-

DESCRIPTION

The PS2535-1 and PS2535L-1 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon darlington connected phototransistor.

A high withstanding voltage between the I/O, the high voltage between the collector and emitter of the transistor, and darlington transistor output enables low-current input.

The PS2535-1 is in a plastic DIP (Dual In-line Package) and the PS2535L-1 is lead bending type (Gull-wing) for surface mount.

FEATURES

- High collector to emitter voltage (VcEo = 350 V)
- High isolation voltage (BV = 5 000 Vr.m.s.)
- High current transfer ratio (CTR = 1 500 % TYP.)
- Ordering number of taping product: PS2535L-1-E3, E4, F3, F4
- Safety standards
 - UL approved: File No. E72422
 - BSI approved: No. 8221/8222
 - DIN EN60747-5-2 (VDE0884 Part2) approved (Option)

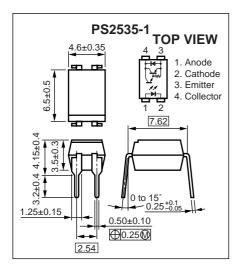
APPLICATIONS

- · Telephone, Exchange equipment
- FAX/MODEM

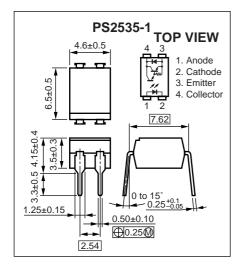
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PACKAGE DIMENSIONS (Unit: mm)

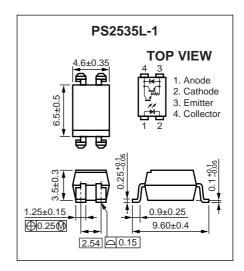
DIP Type (New package)



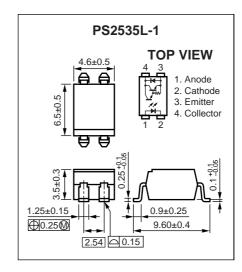
DIP Type



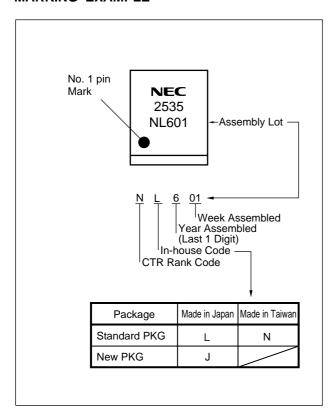
Lead Bending Type (New package)



Lead Bending Type



★ MARKING EXAMPLE



★ ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS2535-1	PS2535-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2535-1
PS2535L-1	PS2535L-1-A			(UL, BSI approved)	
PS2535L-1-E3	PS2535L-1-E3-A		Embossed Tape 1 000 pcs/reel		
PS2535L-1-E4	PS2535L-1-E4-A				
PS2535L-1-F3	PS2535L-1-F3-A		Embossed Tape 2 000 pcs/reel		
PS2535L-1-F4	PS2535L-1-F4-A				
PS2535-1-V	PS2535-1-V-A		Magazine case 100 pcs	DIN EN60747-5-2	
PS2535L-1-V	PS2535L-1-V-A			(VDE0884 Part2)	
PS2535L-1-V-E3	PS2535L-1-V-E3-A		Embossed Tape 1 000 pcs/reel	Approved (Option)	
PS2535L-1-V-E4	PS2535L-1-V-E4-A				
PS2535L-1-V-F3	PS2535L-1-V-F3-A		Embossed Tape 2 000 pcs/reel		
PS2535L-1-V-F4	PS2535L-1-V-F4-A				

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	ĪF	50	mA
	Reverse Voltage	VR	6	V
	Power Dissipation Derating	⊿P₀/°C	0.7	mW/°C
	Power Dissipation	PD	70	mW
	Peak Forward Current *1	IFP	0.5	Α
Transistor	Collector to Emitter Voltage	Vceo	350	V
	Emitter to Collector Voltage	Veco	0.3	V
	Collector Current	lc	120	mA
	Power Dissipation Derating	⊿Pc/°C	2.0	mW/°C
	Power Dissipation	Pc	200	mW
Isolation Voltage *2		BV	5 000	Vr.m.s.
Operating Ambient Temperature		TA	−55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

^{*1} PW = 100 μ s, Duty Cycle = 1%

^{*2} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60% between input and output Pins 1-2 shorted together, 3-4 shorted together.

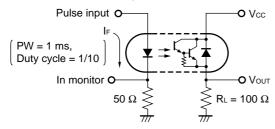
ELECTRICAL CHARACTERISTICS (TA = 25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	I _F = 10 mA		1.2	1.4	V
	Reverse Current	lr	V _R = 5 V			5	μА
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		15		pF
Transistor	Collector to Emitter Dark Current	ICEO	Vce = 350 V, I _F = 0 mA			400	nA
Coupled	Current Transfer Ratio	CTR	I _F = 1 mA, V _{CE} = 2 V	400	1 500	5 500	%
	Collector Saturation Voltage	VCE (sat)	IF = 1 mA, Ic = 2 mA			1.0	V
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.6		pF
	Rise Time *2	tr	$Vcc = 5 \text{ V}, \text{ Ic} = 10 \text{ mA}, \text{ RL} = 100 \Omega$		18		μs
	Fall Time *2	tf			5		

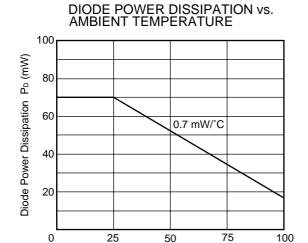
*1 CTR rank

N: 400 to 5 500 (%) L: 1 500 to 5 500 (%)

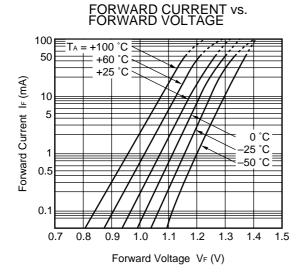
*2 Test circuit for switching time



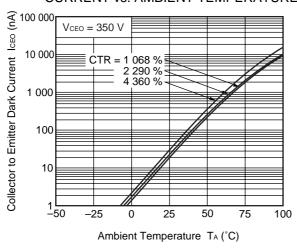
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



Ambient Temperature T_A (°C)

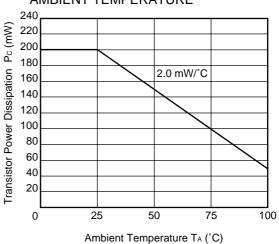


COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

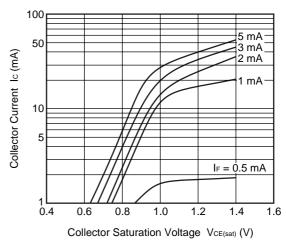


Remark The graphs indicate nominal characteristics.

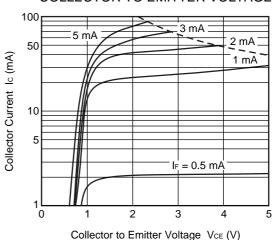
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



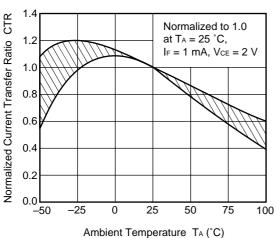
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



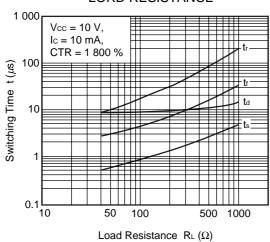
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERTURE

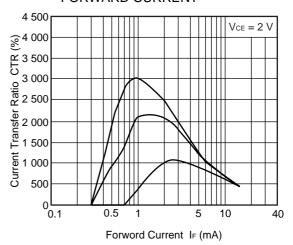


SWITCHING TIME vs. LORD RESISTANCE

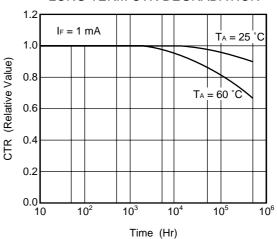


Remark The graphs indicate nominal characteristics.

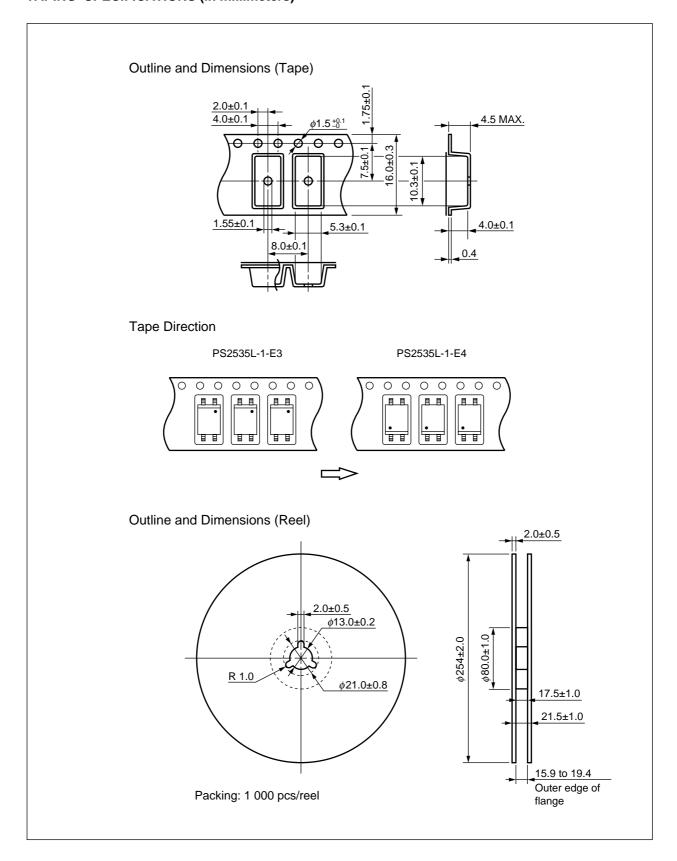
CURRENT TRANSFER RATIO vs. FORWARD CURRENT

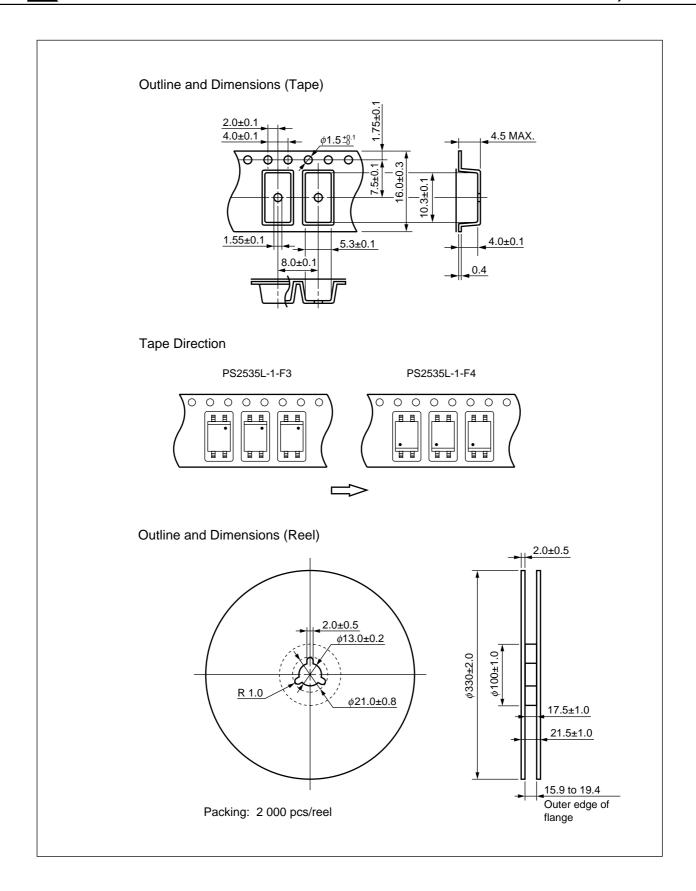


LONG TERM CTR DEGRADATION



TAPING SPECIFICATIONS (in millimeters)





NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

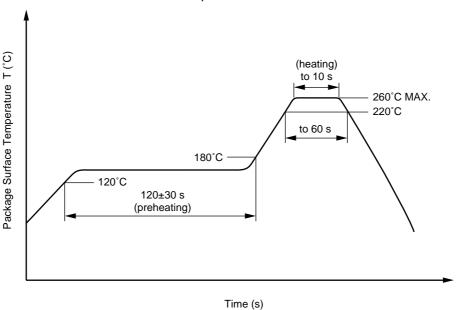
• Peak reflow temperature 260°C or below (package surface temperature)

Time of peak reflow temperature
 Time of temperature higher than 220°C
 60 seconds or less

Time to preheat temperature from 120 to 180°C 120±30 s
 Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

• Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Flux
 Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

★ (3) Soldering by soldering iron

Peak temperature (lead part temperature) 350°C or below
 Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.

(b) Please be sure that the temperature of the package would not be heated over 100°C.

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

★ 3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The -AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)		on contained devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not De	etected	
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	DE < 1000 PPM Not Detected		etected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerting the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.